



# PST KP738

## HIGH POWER PHASE CONTROL THYRISTOR FOR PHASE CONTROL APPLICATIONS

### Features :

- Blocking Capability up to 2200 V
- High dV/dt Capability
- All Diffused Structure
- Amplifying Gate Configuration
- Rugged Ceramic Hermetic Package

### ELECTRICAL CHARACTERISTICS AND RATINGS

#### Blocking

Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Repetitive peak reverse voltage	$V_{RRM}$		2200		V	$T_j = -40\text{ }^{\circ}\text{C}$ to $125\text{ }^{\circ}\text{C}$
Repetitive peak off-state voltage	$V_{DRM}$		2200		V	$T_j = -40\text{ }^{\circ}\text{C}$ to $125\text{ }^{\circ}\text{C}$
Non repetitive peak reverse voltage	$V_{RSM}$		2300		V	$T_j = -40\text{ }^{\circ}\text{C}$ to $125\text{ }^{\circ}\text{C}$
Repetitive peak reverse current	$I_{RRM}$		200		mA	$T_j = T_{jmax}$ , $V = V_{RRM}$
Repetitive peak off-state current	$I_{DRM}$		200		mA	$T_j = T_{jmax}$ , $V = V_{DRM}$

#### Conducting

Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Average value of on-state current	$I_{T(AV)}$		3080		A	50 Hz sine wave, $180^{\circ}$ conduction, $T_c = 85\text{ }^{\circ}\text{C}$
RMS value of on-state current	$I_{T(RMS)}$		4836		A	50 Hz sine wave, $180^{\circ}$ conduction, $T_c = 85\text{ }^{\circ}\text{C}$
Surge non repetitive current	$I_{TSM}$		57		kA	50 Hz sine wave Half cycle
I square t	$I^2 t$		16245		$\text{kA}^2\text{s}$	$V_R = 0$ $T_j = 125\text{ }^{\circ}\text{C}$
Peak on-state voltage	$V_{TM}$		1.15		V	On-state current 2000 A, $T_j = T_{jmax}$
Threshold voltage	$V_{T(TO)}$		0.94		V	$T_j = T_{jmax}$
On-state slope resistance	$r_T$		0.104		$\text{m}\Omega$	$T_j = T_{jmax}$
Holding current	$I_H$			100	mA	$V_D = 24\text{ V}$ ; $I_T = 2.5\text{ A}$
Latching current	$I_L$			400	mA	$V_D = 24\text{ V}$ ; $R_L = 12\ \Omega$

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### Triggering

Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Gate current	$I_{GT}$		300		mA	$V_D = 6\text{ V}; R_L = 3\ \Omega; T_j = -40\text{ }^\circ\text{C}$
			200		mA	$V_D = 6\text{ V}; R_L = 3\ \Omega; T_j = 25\text{ }^\circ\text{C}$
			125		mA	$V_D = 6\text{ V}; R_L = 3\ \Omega; T_j = 25\text{ }^\circ\text{C}$
Gate voltage	$V_{GT}$		5		V	$V_D = 6\text{ V}; R_L = 3\ \Omega; T_j = -40\text{ }^\circ\text{C}$
			3		V	$V_D = 6\text{ V}; R_L = 3\ \Omega; T_j = 0 \div 125\text{ }^\circ\text{C}$
		0.3			V	$V_D = V_{DRM}; R_L = 10\text{ k}\Omega; T_j = 125\text{ }^\circ\text{C}$
Peak gate current	$I_{GM}$		10		A	
Peak reverse gate voltage	$V_{RGM}$		5		V	
Peak gate power dissipation	$P_{GM}$		200		W	
Average gate power dissipation	$P_{G(AV)}$		5		W	

### Switching

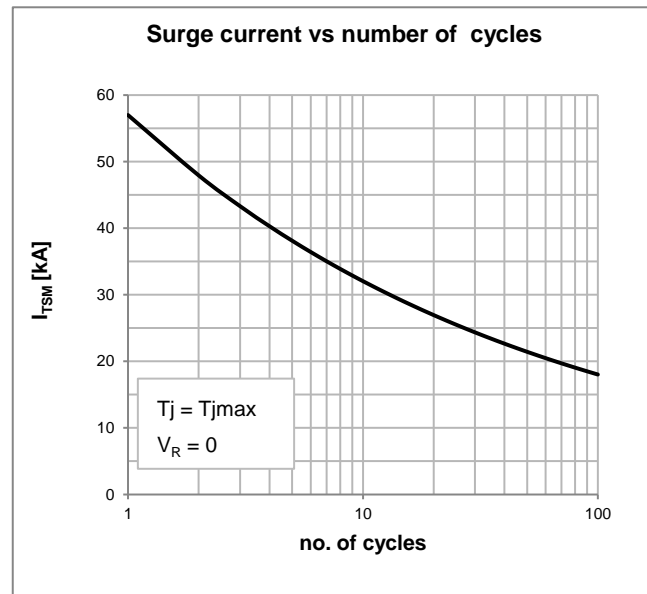
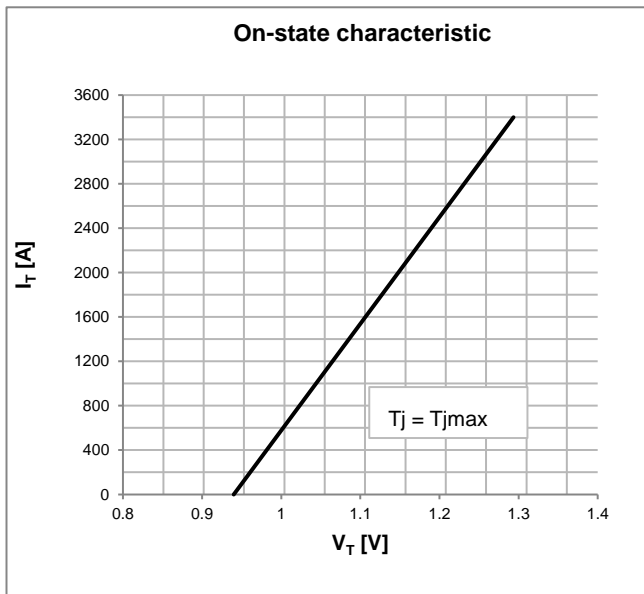
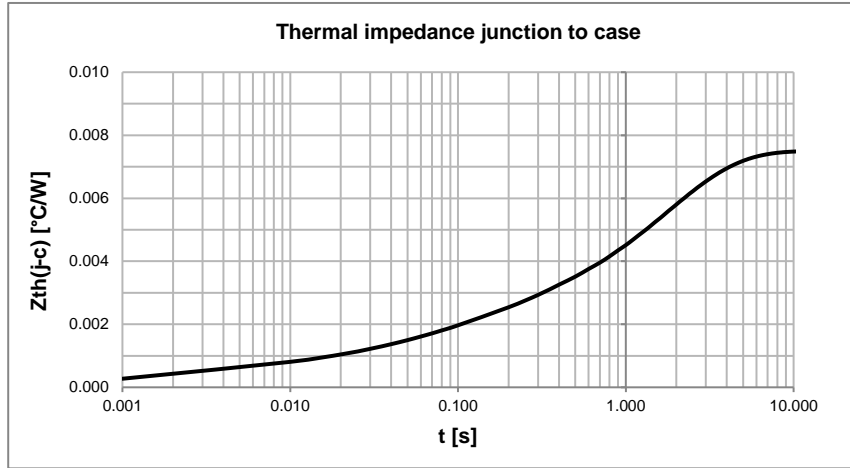
Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Critical rate of rise of on-state current	$di/dt$	200			A/ $\mu$ s	Switching from $V_{DRM} \leq 1000\text{ V}$
Critical rate of rise of on-state voltage	$dv/dt$	500			V/ $\mu$ s	Linear ramp up to 80% of $V_{DRM}$
Gate controlled delay time	$t_d$		3	2.5	$\mu$ s	$I_{TM} = 50\text{ A}; V_D = 1500\text{ V}; V_G = 20\text{ V}$ $R_G = 20\ \Omega; t_r = 0.1\ \mu\text{s}; t_p = 20\ \mu\text{s}$
Turn-off time	$t_q$		400	250	$\mu$ s	$I_{TM} = 500\text{ A}; di/dt = 25\text{ A}/\mu\text{s}; V_R \geq 50\text{ V}$ $dV/dt = 200\text{ V}/\mu\text{s}$ linear to 80% $V_{DRM}$ $V_G = 0\text{ V}; T_j = 125\text{ }^\circ\text{C}$
Reverse recovery charge	$Q_{rr}$			2000	$\mu$ C	$I_T = 2000\text{ A}$ $di/dt = 20\text{ A}/\mu\text{s}$
Reverse recovery current	$I_{rr}$			250	A/ $\mu$ s	$V_R \geq 50\text{ V}$ $T_j = T_{jmax}$

### Thermal and mechanical

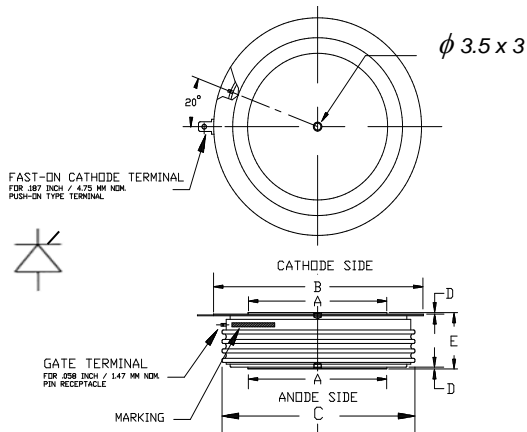
Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Operating temperature	$T_j$	-40	125		$^\circ\text{C}$	
Storage temperature	$T_{stg}$	-40	125		$^\circ\text{C}$	
Thermal resistance junction to case	$R_{th(j-c)}$		0.008		$^\circ\text{C}/\text{W}$	Double side cooled, DC
Thermal resistance case to sink	$R_{th(c-s)}$		0.002		$^\circ\text{C}/\text{W}$	Double side cooled, mounting surfaces smooth, flat and greased
Mounting force	$F$	40	50		kN	
Weight	$W$			1600	g	

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### OUTLINE AND DIMENSIONS



	A	B	C	E
mm	84	118	110	35+/-1

- All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink surfaces with flatness < 0.03 mm and roughness < 2µm